

### NCE P-Channel Enhancement Mode Power MOSFET

### **Description**

The NCE3415 uses advanced trench technology to provide excellent  $R_{\rm DS(ON)}$ , low gate charge and operation with gate voltages as low as 1.8V. This device is suitable for use as a load switch or in PWM applications .It is ESD protested.

### **General Features**

•  $V_{DS} = -20V, I_D = -4A$ 

 $R_{DS(ON)}$  < 60m $\Omega$  @  $V_{GS}$ =-2.5V

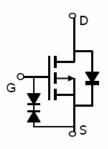
 $R_{DS(ON)}$  < 45m $\Omega$  @  $V_{GS}$ =-4.5V

ESD Rating: 2500V HBM

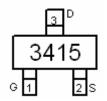
- High Power and current handing capability
- Lead free product is acquired
- Surface mount package

### **Application**

- PWM application
- Load switch



Schematic diagram



Marking and pin Assignment



SOT-23 top view

### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
3415	NCE3415	SOT-23	Ø180mm	8 mm	3000 units

### Absolute Maximum Ratings (TA=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit V	
Drain-Source Voltage	V <sub>DS</sub>	-20		
Gate-Source Voltage	V <sub>G</sub> S	±10	V	
Drain Current-Continuous	I <sub>D</sub>	-4	Α	
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	-30	Α	
Maximum Power Dissipation	P <sub>D</sub>	1.4	W	
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 150	$^{\circ}$	

### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	89.3	°C/W
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### Electrical Characteristics (TA=25°C unless otherwise noted)

Parameter	Symbol Condition		Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250μA	-20		-	V



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# NCE3415

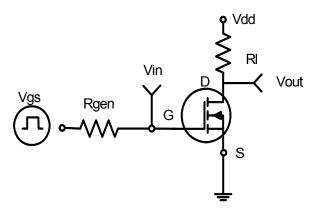
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±10V,V <sub>DS</sub> =0V	-	-	±10	μA
On Characteristics (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =-250μA	-0.35	-0.55	-0.9	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-4A	-	34	45	mΩ
Dialii-Source Oil-State Resistance		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-4A	-	44	60	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =-5V,I <sub>D</sub> =-4A	8	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	\/ - 40\/\/ -0\/	-	950	-	PF
Output Capacitance	Coss	$V_{DS}$ =-10V, $V_{GS}$ =0V, F=1.0MHz	-	165	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0IVID2	-	120	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	12		nS
Turn-on Rise Time	t <sub>r</sub>	V <sub>DD</sub> =-10V,R <sub>L</sub> =2. 5Ω	_	10		nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =-4.5 $V$ , $R_{GEN}$ =3 $\Omega$	-	19		nS
Turn-Off Fall Time	t <sub>f</sub>		-	25		nS
Total Gate Charge	Qg	\/ - 40\/   - 40	-	12		nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =-10V, $I_{D}$ =-4A, $V_{GS}$ =-4.5V	_	1.4	-	nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =-4.5V	-	3.6	-	nC
Drain-Source Diode Characteristics			•			
Diode Forward Voltage (Note 3)	$V_{SD}$	V <sub>GS</sub> =0V,I <sub>S</sub> =-4A	-	-	-1.2	V
Diode Forward Current (Note 2)	Is		-	-	-4	Α

### Notes:

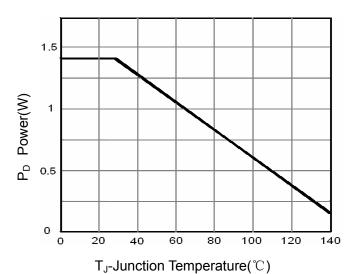
- $\textbf{1.} \ \textbf{Repetitive Rating: Pulse width limited by maximum junction temperature}.$
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production



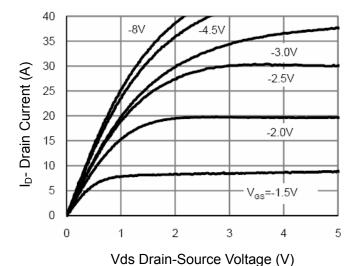
## **Typical Electrical and Thermal Characteristics**



**Figure 1:Switching Test Circuit** 



**Figure 3 Power Dissipation** 



**Figure 5 Output Characteristics** 

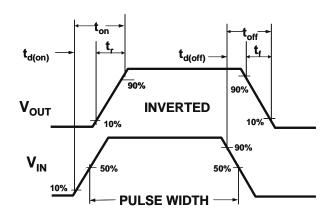


Figure 2:Switching Waveforms

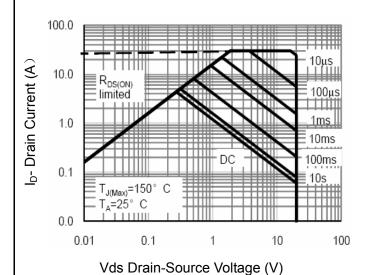


Figure 4 Safe Operation Area

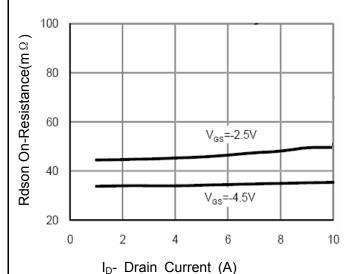
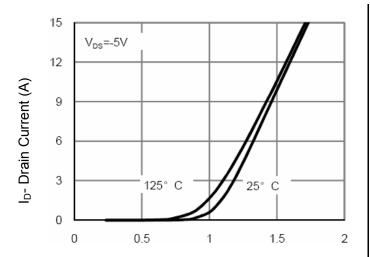


Figure 6 Drain-Source On-Resistance





Vgs Gate-Source Voltage (V)
Figure 7 Transfer Characteristics

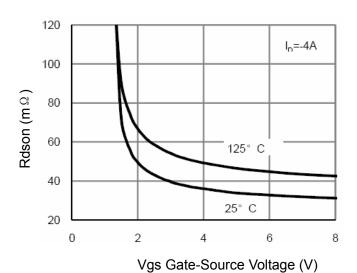


Figure 9 Rdson vs Vgs

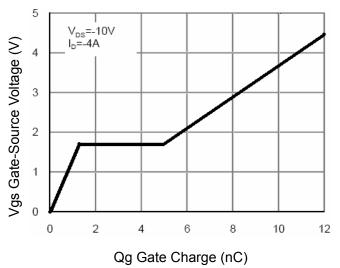


Figure 11 Gate Charge

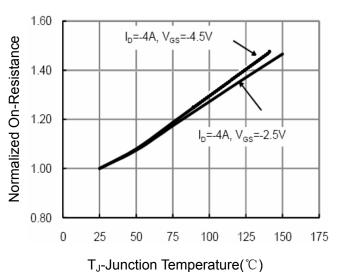


Figure 8 Drain-Source On-Resistance

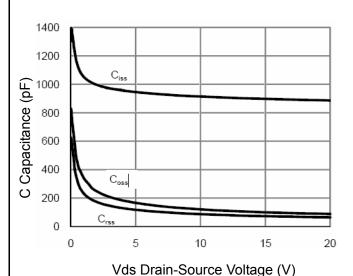


Figure 10 Capacitance vs Vds

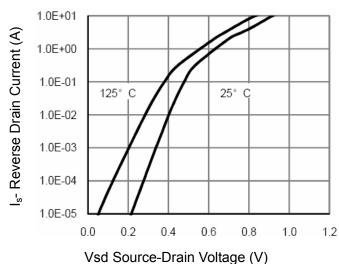
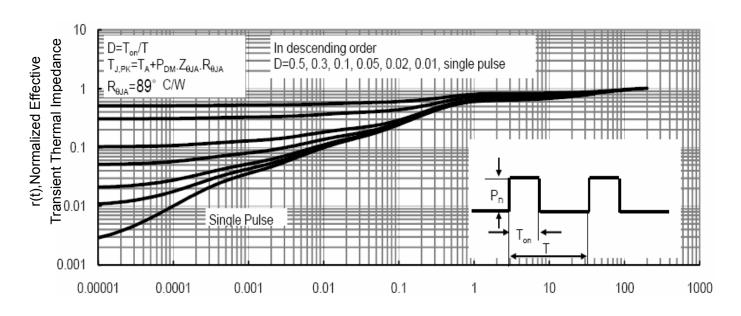


Figure 12 Source- Drain Diode Forward

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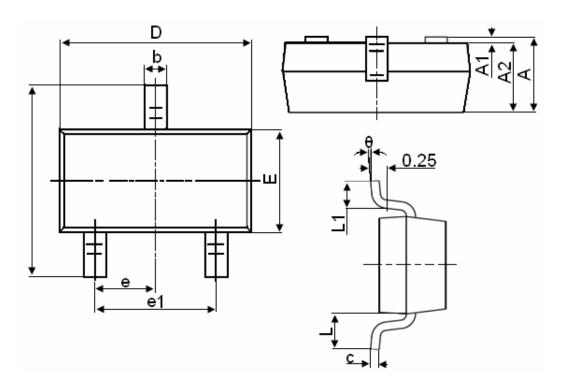


Square Wave Pluse Duration(sec)

**Figure 13 Normalized Maximum Transient Thermal Impedance** 



# **SOT-23 Package Information**



Symbol	Dimensions in Millimeters				
Symbol	MIN.	MAX.			
Α	0.900	1.150			
A1	0.000	0.100			
A2	0.900	1.050			
b	0.300	0.500			
С	0.080	0.150			
D	2.800	3.000			
E	1.200	1.400			
E1	2.250	2.550			
е		0.950TYP			
e1	1.800	2.000			
L	0.550REF				
L1	0.300	0.500			
θ	0°	8°			

### Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



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